NSN 5962-01-260-3900

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View Online at https://aerobasegroup.com/nsn/5962-01-260-3900

Body Length:

0.840 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

0.185 inches

Maximum Power Dissipation Rating:

794.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

1260-01-208-6448 mast mounted si

Features Provided:

Hermetically sealed and burn in and programmable and schottky and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Case Outline Source And Designator:

D-2 mil-m-38510

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminal surface option gold

Precious Material:

Gold

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0